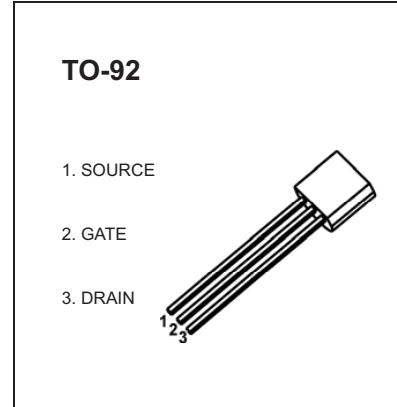


TO-92 Plastic-Encapsulate MOSFETS

2N7000

MOSFET (N-Channel)

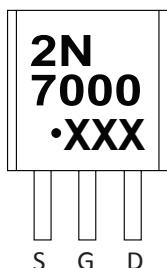
| V_{(BR)DSS} | R_{DS(on)MAX} | I_D |
|----------------------------|------------------------------|----------------------|
| 60 V | 5Ω@10V | 200mA |
| | 6Ω@4.5V | |



FEATURE

- High density cell design for low R_{DS(ON)}
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability

MARKING



2N7000=Device code

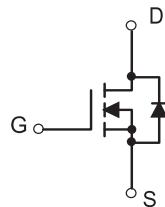
Solid dot=Green molding compound device,
if none, the normal device

XXX=Code

APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

Equivalent Circuit



ORDERING INFORMATION

| Part Number | Package | Packing Method | Pack Quantity |
|-------------|---------|----------------|---------------|
| 2N7000 | TO-92 | Bulk | 1000pcs/Bag |
| 2N7000-TA | TO-92 | Tape | 2000pcs/Box |

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|---------------------------------------------|------------------|------------|------|
| Drain-Source Voltage | V _{DS} | 60 | V |
| Continuous Drain Current | I _D | 0.2 | A |
| Power Dissipation | P _D | 0.625 | W |
| Thermal Resistance from Junction to Ambient | R _{θJA} | 200 | °C/W |
| Junction Temperature | T _J | 150 | °C |
| Storage Temperature | T _{stg} | -55 ~ +150 | |

MOSFET ELECTRICAL CHARACTERISTICS

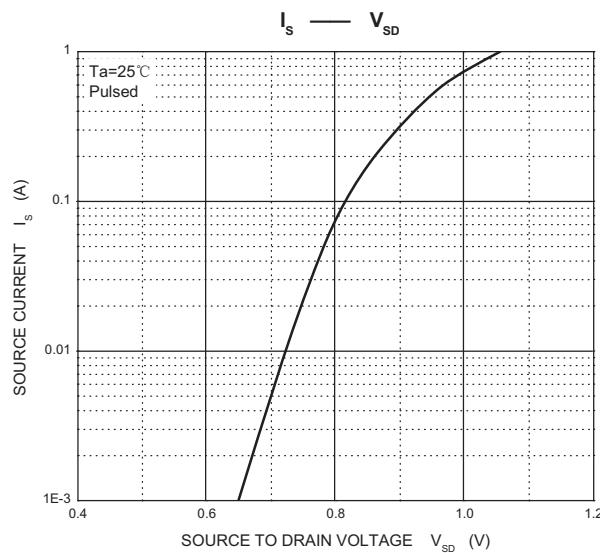
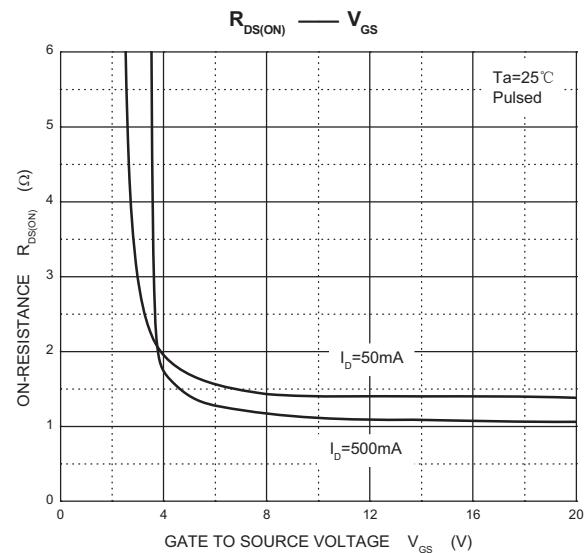
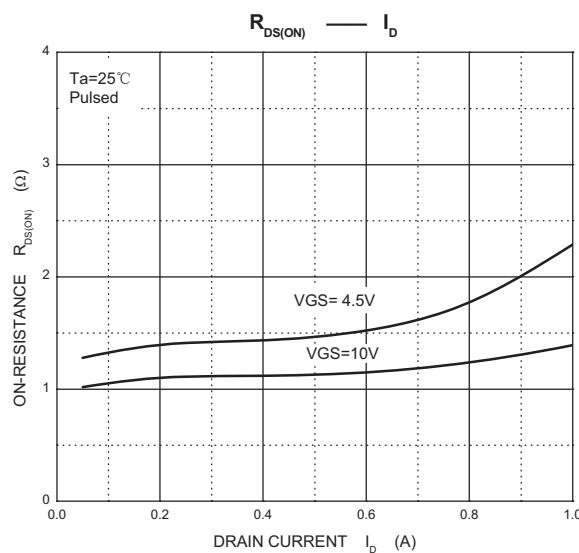
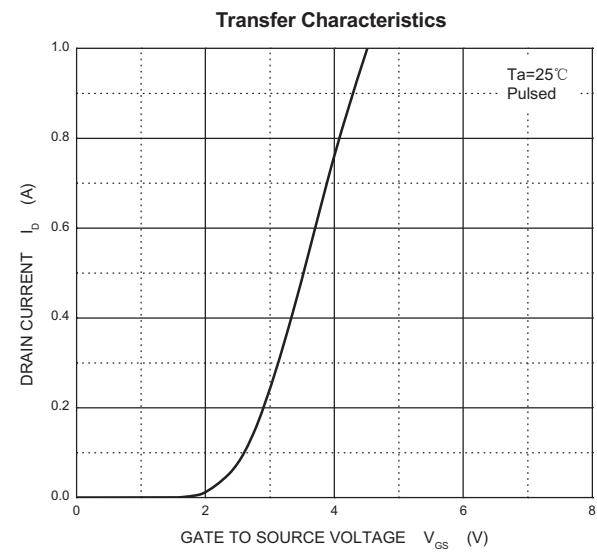
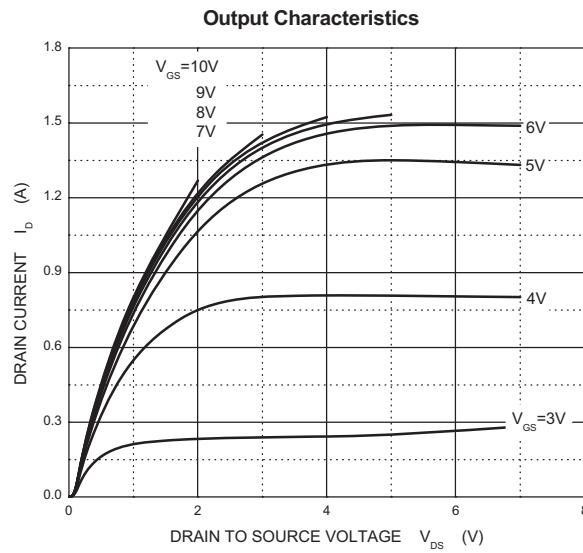
$T_a=25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|----------------------------------------|-----------------------------|---------------------------------------------------------------------------------------------------------------|-----|-----|----------|---------------|
| Drain-Source Breakdown Voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{\text{GS}}=0\text{ V}, I_D=10\mu\text{A}$ | 60 | | | V |
| Gate-Threshold Voltage* | $V_{(\text{GS})\text{th}}$ | $V_{\text{DS}}=V_{\text{GS}}, I_D=1\text{mA}$ | 0.8 | | 3 | |
| Gate-body Leakage | I_{GSS} | $V_{\text{DS}}=0\text{ V}, V_{\text{GS}}=\pm 15\text{ V}$ | | | ± 10 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{\text{DS}}=60\text{ V}, V_{\text{GS}}=0\text{ V}$ | | | 1 | μA |
| On-state Drain Current | $I_{\text{D}(\text{ON})}$ | $V_{\text{GS}}=4.5\text{ V}, V_{\text{DS}}=10\text{ V}$ | 75 | | | mA |
| Drain-Source On-Resistance* | $R_{\text{DS}(\text{on})}$ | $V_{\text{GS}}=4.5\text{V}, I_D=75\text{mA}$ | | | 6 | Ω |
| | | $V_{\text{GS}}=10\text{V}, I_D=500\text{mA}$ | | | 5 | |
| Forward Trans conductance* | g_{fs} | $V_{\text{DS}}=10\text{ V}, I_D=200\text{mA}$ | 100 | | | ms |
| Drain-source on-voltage* | $V_{\text{DS}(\text{on})}$ | $V_{\text{GS}}=10\text{V}, I_D=500\text{mA}$ | | | 2.5 | V |
| | | $V_{\text{GS}}=4.5\text{V}, I_D=75\text{mA}$ | | | 0.45 | V |
| Input Capacitance ** | C_{iss} | $V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$ | | | 60 | pF |
| Output Capacitance ** | C_{oss} | | | | 25 | |
| Reverse Transfer Capacitance ** | C_{rss} | | | | 5 | |
| Turn-on Time ** | $t_{\text{d}(\text{on})}$ | $V_{\text{DD}}=15\text{ V}, R_L=30\Omega$ $I_D=500\text{mA}, V_{\text{GEN}}=10\text{ V}$ $R_G=25\Omega$ | | | 10 | ns |
| Turn-off Time ** | $t_{\text{d}(\text{off})}$ | | | | 10 | |

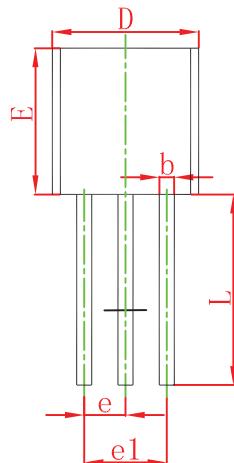
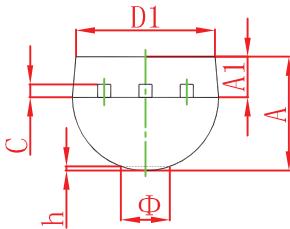
*Pulse test

**These parameters have no way to verify.

Typical Characteristics

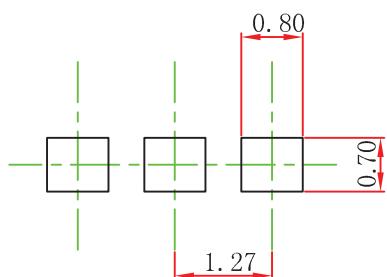


TO-92 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 3.300 | 3.700 | 0.130 | 0.146 |
| A1 | 1.100 | 1.400 | 0.043 | 0.055 |
| b | 0.380 | 0.550 | 0.015 | 0.022 |
| c | 0.360 | 0.510 | 0.014 | 0.020 |
| D | 4.300 | 4.700 | 0.169 | 0.185 |
| D1 | 3.430 | | 0.135 | |
| E | 4.300 | 4.700 | 0.169 | 0.185 |
| e | 1.270 TYP | | 0.050 TYP | |
| e1 | 2.440 | 2.640 | 0.096 | 0.104 |
| L | 14.100 | 14.500 | 0.555 | 0.571 |
| Φ | | 1.600 | | 0.063 |
| h | 0.000 | 0.380 | 0.000 | 0.015 |

TO-92 Suggested Pad Layout



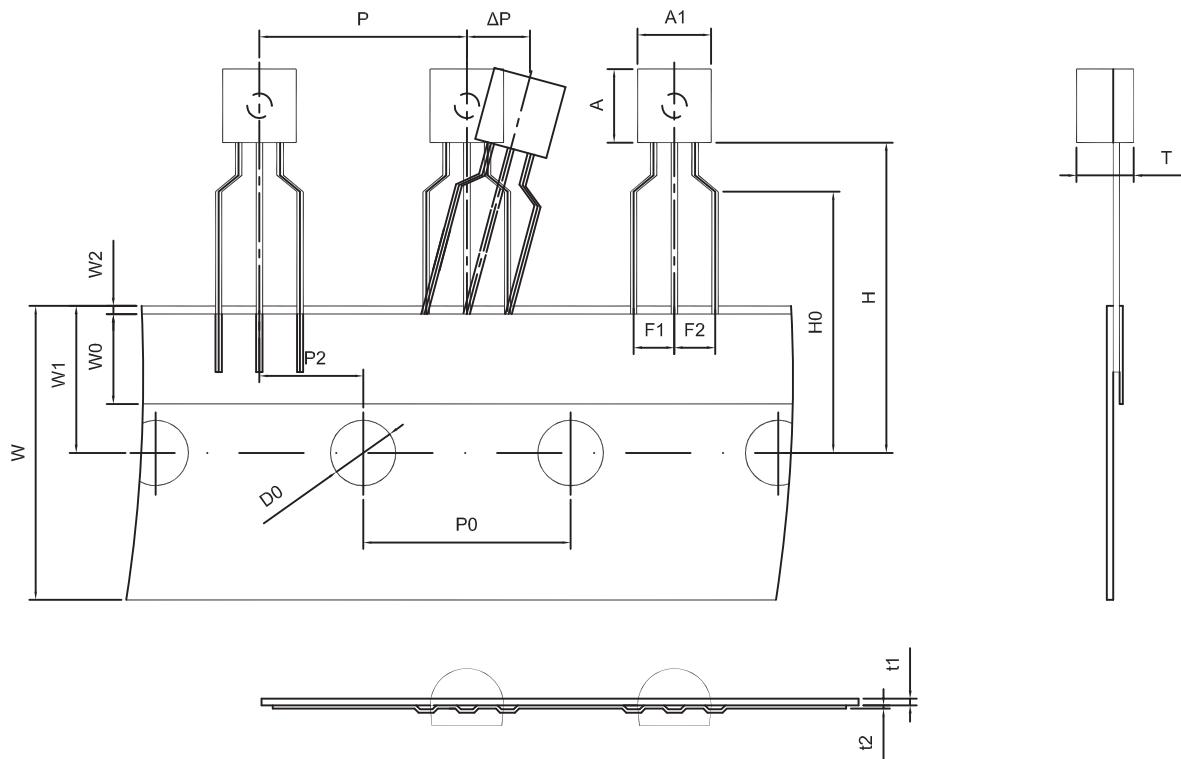
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

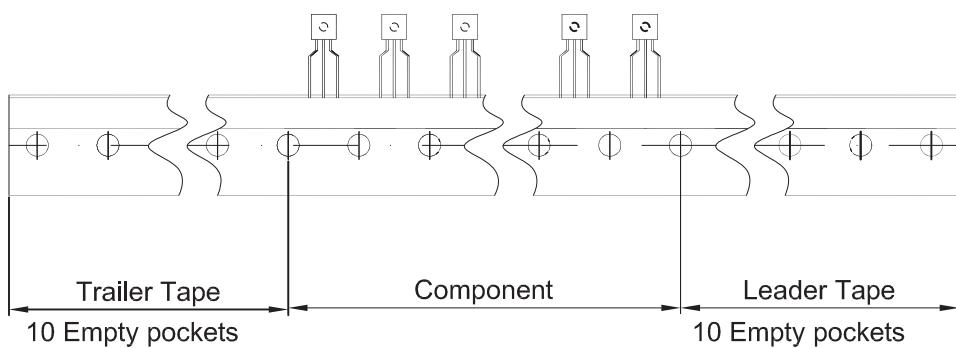
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TO-92 PACKAGE TAPEING DIMENSION



Dimensions are in millimeter

| A1 | A | T | P | P0 | P2 | F1 | F2 | W |
|-----|-----|----------|------|------|------|-----|-----|------|
| 4.5 | 4.5 | 3.5 | 12.7 | 12.7 | 6.35 | 2.5 | 2.5 | 18.0 |
| W0 | W1 | W2 | H | H0 | D0 | t1 | t2 | ΔP |
| 6.0 | 9.0 | 1.0 MAX. | 19.0 | 16.0 | 4.0 | 0.4 | 0.2 | 0 |



| Package | Box | Box Size(mm) | Carton | Carton Size(mm) |
|---------|----------|--------------|------------|-----------------|
| TO-92 | 2000 pcs | 333×162×43 | 20,000 pcs | 350×340×250 |